






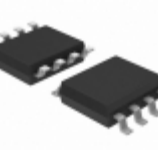
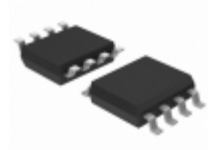
	<h2>SI4124DY-T1-E3</h2>
	<p>Hersteller-Teilenummer: SI4124DY-T1-E3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET N-CH 40V 20.5A 8-SOIC</p> <p>Datenblätter:  SI4124DY-T1-E3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 35439 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI4124DY-T1-E3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET N-CH 40V 20.5A 8-SOIC
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	35439 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	8-SOIC (0.154", 3.90mm Width)
Supplier Device-Gehäuse	8-SO
Verlustleistung (max)	2.5W (Ta), 5.7W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	40V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	20.5A (Tc)
Rds On (Max) @ Id, Vgs	7.5 mOhm @ 14A, 10V
VGS (th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	77nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	3540pF @ 20V
Verpackung	Tape & Reel (TR)



















































SI4124DY-T1-E3 ist neu im Original, Suche SI4124DY-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI4124DY-T1-E3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI4124DY-T1-E3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI4123-D-GTR Energy Micro (Silicon Labs) IC SYNTHESIZER RF1/IF 24TSSOP</p>	 <p>SI4126-BMR SILICON SI4126-BMR SILICON</p>	 <p>SI4126-BM Energy Micro (Silicon Labs) IC SYNTHESIZER WLAN RF2/IF 28MLP</p>	 <p>SI4123M-EVB Energy Micro (Silicon Labs) BOARD EVALUATION FOR SI4123</p>
 <p>SI4126-F-BM Energy Micro (Silicon Labs) IC SYNTHESIZER RF2/IF 28MLP</p>	 <p>SI4124DY VISHAY VISHAY SOP-8</p>	 <p>SI4124DY-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 40V 20.5A 8- SOIC</p>	 <p>SI4124DY-T1-GE3 Vishay / Siliconix MOSFET N-CH 40V 20.5A 8- SOIC</p>

heiße Teile

Mehr

 SI4102DY-T1-GE3	 SI4102DY-T1-GE3	 SI4104DY-T1-GE3	 SI4104DY-T1-GE3	 SI4108DY-T1-GE3
 SI4108DY-T1-GE3	 SI4110DY-T1-GE3	 SI4110DY-T1-GE3	 SI4112-D-GM	 SI4113-BMR
 SI4114DY	 SI4114DY-T1-E3	 SI4114DY-T1-E3	 SI4114DY-T1-GE3	 SI4114DY-T1-GE3
 SI4116DY	 SI4116DY-T1-E3	 SI4116DY-T1-E3	 SI4116DY-T1-GE3	 SI4116DY-T1-GE3
 SI4122-BTR	 SI4122-D-GMR	 SI4122DY-T1-E3	 SI4122G-BMR	 SI4123-BM
 SI4124DY-T1-E3	 SI4124DY-T1-GE3	 SI4124DY-T1-GE3	 SI4126-BMR	 SI4126DY-T1-E3
 SI4128BDY	 SI4128BDY-T1-GE3	 SI4128BDY-T1-GE3	 SI4128DY	 SI4128DY-T1
 SI4128DY-T1-E3	 SI4128DY-T1-E3	 SI4128DY-T1-GE3	 SI4128DY-T1-GE3	 SI4133-D-GM
 SI4133G-BT	 SI4133T-BM	 SI4133T-BMR	 SI4133W-BMR	 SI4133X1-BMR
 SI4134DY	 SI4134DY-T1	 SI4134DY-T1-E3	 SI4134DY-T1-E3	 SI4134DY-T1-GE3

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